# FemtoClock® Crystal-to-0.7V Differential HCSL Clock Generator

**DATA SHEET** 

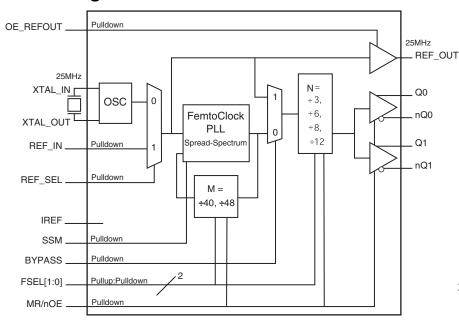
### **General Description**

The ICS841402I is an optimized PCIe and sRIO clock generator. The device uses a 25MHz parallel resonant crystal to generate 100MHz, 125MHz, 200MHz and 400MHz clock signals, replacing solutions requiring multiple oscillator and fanout buffer solutions. The device has excellent phase jitter suitable to clock components requiring precise and low jitter PCIe, sRIO or both clock signals. The device also supports a configurable spread-spectrum generation for PCIe applications. Designed for telecom, networking and industrial applications, the ICS841402I can also drive the high-speed sRIO and PCIe SerDes clock inputs of communications processors, DSPs, switches and bridges.

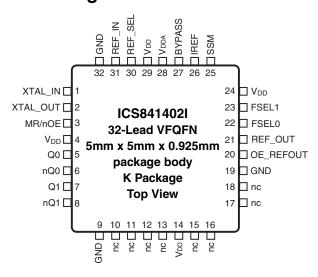
#### **Features**

- Two 0.7V differential HCSL outputs: configurable for PCIe (100MHz or 200MHz) and sRIO (125MHz) clock signals
- One LVCMOS/LVTTL reference clock output
- Selectable crystal oscillator interface, 25MHz, 18pF parallel resonant crystal or LVCMOS/LVTTL single-ended reference clock input
- Supports the following output frequencies: 100MHz, 125MHz, 200MHz or 400MHz
- VCO frequency range: 950MHz 1.25GHz
- Configurable spread-spectrum generation for PCIe
- PLL bypass and output enable
- RMS phase jitter @ 200MHz, using a 25MHz crystal (12kHz – 20MHz): 1.21ps (typical)
- PCI Express (2.5 Gb/S), Gen 2 (5 Gb/s) and Gen 3 (8 Gb/s) jitter compliant (REF\_OUT disabled)
- Full 3.3V operating supply
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) packages

# **Block Diagram**



# **Pin Assignment**





**Table 1. Pin Descriptions** 

Number	Number Name Type Description		Description	
1, 2	XTAL_IN, XTAL_OUT	Input		Parallel resonant crystal interface. XTAL_OUT is the output, XTAL_IN is the input. (PLL reference.)
3	MR/nOE	Input	Pulldown	Master reset. LVCMOS/LVTTL interface levels. See Table 3D.
4, 14, 24, 29	$V_{DD}$	Power		Core supply pins.
5, 6	Q0, nQ0	Output		Differential output pair. HCSL interface levels.
7, 8	Q1, nQ1	Output		Differential output pair. HCSL interface levels.
9, 19, 32	GND	Power		Power supply ground.
10, 11, 12, 13, 15, 16, 17, 18	nc	Unused		No connect.
20	OE_REFOUT	Input	Pulldown	Output enable pin. LVCMOS/LVTTL interface levels. See Table 3F.
21	REF_OUT	Output		Reference clock output. LVCMOS/LVTTL interface levels. In PCIe Gen 2 and Gen 3 applications, the REF_OUT output should be disabled.
22	F_SEL0	Input	Pulldown	Output frequency select pin. LVCMOS/LVTTL interface levels. See Table 3B.
23	F_SEL1	Input	Pullup	Output frequency select pin. LVCMOS/LVTTL interface levels. See Table 3B.
25	SSM	Input	Pulldown	Spread-spectrum selection. LVCMOS/LVTTL interface levels. See Table 3A.
26	IREF	Output		0.7V current reference resistor output. A fixed precision resistor (475 $\Omega$ ) from this pin to ground provides a reference current used for differential current-mode Qx, nQx clock outputs.
27	BYPASS	Input	Pulldown	Selects PLL operation/PLL bypass operation. See Table 3C. LVCMOS/LVTTL interface levels.
28	$V_{DDA}$	Power		Analog supply pin.
30	REF_SEL	Input	Pulldown	Reference select. Selects the input reference source. LVCMOS/LVTTL interface levels. See Table 3E.
31	REF_IN	Input	Pulldown	LVCMOS/LVTTL PLL reference clock input.

NOTE: Pulldown and Pullup refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

# **Table 2. Pin Characteristics**

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance				4		pF
R <sub>PULLDOWN</sub>	Input Pulldown Resistor				51		kΩ
R <sub>PULLUP</sub>	Input Pullup Resistor				51		kΩ
R <sub>OUT</sub>	Output Impedance	REF_OUT			27		Ω



# **Function Tables**

# Table 3A. Spread-Spectrum Modulation (SSM) Function Table ( $f_{REF} = 25MHz$ )

Input	Outputs
SSM	Q[0:1], nQ[0:1]
0	SSM off (default)
1	SSM on (at 32kHz, -0.5%)

# Table 3B. FSEL Function Table ( $f_{REF} = 25MHz$ )

Inputs				Outputs
FSEL1	FSEL0	M Divider	N Divider	Q[0:1], nQ[0:1]
0	0	48	12	VCO/12 (100MHz) PCIe
0	1	40	8	VCO/8 (125MHz) sRIO
1	0	48	6	VCO/6 (200MHz) PCIe (default)
1	1	48	3	VCO/3 (400MHz)

#### **Table 3C. BYPASS Function Table**

Input						
BYPASS PLL Configuration						
0	PLL on (default)					
1	PLL bypassed (Q[0:1], nQ[0:1] = f <sub>REF</sub> /N)					

#### Table 3E. REF\_SEL Function Table

Input						
REF_SEL	Input Reference					
0	XTAL (default)					
1	REF_IN					

#### Table 3D. MR/nOE Function Table

Input					
MR/nOE	Function <sup>NOTE1</sup>				
0	Outputs enabled (default)				
1	Device reset, outputs disabled (High Impedance)				

NOTE 1: Asynchronous function.

#### Table 3F. OE\_REFOUT Function Table

Input						
OE_REFOUT Function						
0	REF_OUT disabled (High Impedance) (default)					
1	REF_OUT enabled					



# **Absolute Maximum Ratings**

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V <sub>DD</sub>	4.6V
Inputs, V <sub>I</sub> XTAL_IN Other Inputs	0V to V <sub>DD</sub> -0.5V to V <sub>DD</sub> + 0.5V
Outputs, V <sub>O</sub>	-0.5V to V <sub>DD</sub> + 0.5V
Package Thermal Impedance, $\theta_{JA}$	37.0°C/W (0 mps)
Storage Temperature, T <sub>STG</sub>	-65°C to 150°C

#### **DC Electrical Characteristics**

Table 4A. Power Supply DC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = -40^{\circ}C$  to  $85^{\circ}C$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Power Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		V <sub>DD</sub> – 0.16	3.3	$V_{DD}$	٧
$I_{DD}$	Power Supply Current	Outputs unterminated			156	mA
I <sub>DDA</sub>	Analog Supply Current	Outputs unterminated			16	mA

#### Table 4B. LVCMOS/LVTTL DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ , $T_A = -40$ °C to 85°C

Symbol	Parameter Input High Voltage		<b>Test Conditions</b>	Minimum	Typical	Maximum	Units
V <sub>IH</sub>				2		V <sub>DD</sub> + 0.3	V
V <sub>IL</sub>	Input Low Volta	ige		-0.3		0.5	٧
I <sub>IH</sub>	Input High Current	REF_IN, REF_SEL, BYPASS, SSM, F_SEL0, MR/nOE, OE_REFOUT	$V_{DD} = V_{IN} = 3.465V$			150	μА
		F_SEL1	$V_{DD} = V_{IN} = 3.465V$			5	μA
I <sub>IL</sub>	Input Low Current	REF_IN, REF_SEL, BYPASS, SSM, F_SEL0, MR/nOE, OE_REFOUT	V <sub>DD</sub> = 3.465V, V <sub>IN</sub> = 0V	-5			μА
		F_SEL1	$V_{DD} = 3.465V, V_{IN} = 0V$	-150			μΑ
V <sub>OH</sub>	Output High Voltage	REF_OUT	I <sub>OH</sub> = -12mA	2.6			V
V <sub>OL</sub>	Output Low Voltage	REF_OUT	I <sub>OL</sub> = 12mA			0.5	V



**Table 5. Crystal Characteristics** 

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation			Fundamental		
Frequency			25		MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF

NOTE: Characterized using an 18pF parallel resonant crystal.

#### **AC Electrical Characteristics**

Table 6A. PCI Express Jitter Specifications,  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = -40^{\circ}C$  to  $85^{\circ}C$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	PCle Industry Specification	Units
t <sub>j</sub> (PCle Gen 1)	Phase Jitter Peak to Peak Note 1, 4	f = 100MHz, 25MHz crystal input Evaluation Band: 0Hz - Nyquist (clock frequency/2)		14.2	30.6	86	ps
t <sub>REFCLK_HF_RMS</sub> (PCle Gen 2)	Phase Jitter RMS; NOTE 2, 4	f = 100MHz, 25MHz Crystal Input High Band: 1.5MHz - Nyquist (clock frequency/2)		0.77	1.4	3.1	ps
t <sub>REFCLK_LF_RMS</sub> (PCle Gen 2)	Phase Jitter RMS; NOTE 2, 4	f= 100MHz, 25MHz Crystal Input Low Band: 10kHz - 1.5MHz		0.17	0.45	3.0	ps
t <sub>REFCLK_LF_RMS</sub> (PCIe Gen 3)	Phase Jitter RMS; NOTE 3, 4	f = 100MHz, 25MHz crystal input Evaluation Band: 0Hz - Nyquist (clock frequency/2)		0.16	0.35	0.8	ps

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions. For additional information, refer to the *PCI Express Application Note section* in the datasheet.

NOTE: PCIe jitter parameters were obtained with Spread Spectum Modulation disabled.

NOTE: PCle Gen 2 and Gen 3 jitter parameters were obtained with REF\_OUT disabled.

NOTE 1: Peak-to-Peak jitter after applying system transfer function for the Common Clock Architecture. Maximum limit for PCI Express Gen 1 is 86ps peak-to-peak for a sample size of 10<sup>6</sup> clock periods.

NOTE 2: RMS jitter after applying the two evaluation bands to the two transfer functions defined in the Common Clock Architecture and reporting the worst case results for each evaluation band. Maximum limit for PCI Express Generation 2 is 3.1ps RMS for t<sub>REFCLK\_HF\_RMS</sub> (High Band) and 3.0ps RMS for t<sub>REFCLK\_LF\_RMS</sub> (Low Band).

NOTE 3: RMS jitter after applying system transfer function for the common clock architecture. This specification is based on the *PCI Express Base Specification Revision 0.7, October 2009* and is subject to change pending the final release version of the specification.

NOTE 4: This parameter is guaranteed by characterization. Not tested in production.



Table 6B. AC Characteristics,  $V_{DD}=3.3V\pm5\%,\,T_{A}=-40^{\circ}C$  to  $85^{\circ}C$ 

Symbol	I Parameter		Test Conditions	Minimum	Typical	Maximum	Units
					100		MHz
f <sub>OUT</sub>		0[0:4] :=0[0:4]			125		MHz
	Output Frequency	Q[0:1], nQ[0:1]			200		MHz
					400		MHz
		REF_OUT			25		MHz
$f_{\text{IN}}$	Input Frequency	REF_IN	REF_SEL = 1, BYPASS = 0			25	MHz
<i>t</i> sk(o)	Output Skew; NOT	E 1, 2				70	ps
	Cycle-to-Cycle Jitter; NOTE 2		$f_{OUT} = 100MHz$ , N = 12, OE_REFOUT = 1, SSM = 0		60	100	ps
tjit(cc)			$f_{OUT} = 125MHz, N = 8,$ $OE\_REFOUT = 1, SSM = 0$		35	92	ps
ijit(OO)			$f_{OUT} = 200MHz$ , N = 6, OE_REFOUT = 1, SSM = 0		20	72	ps
			$f_{OUT} = 400MHz, N = 3,$ $OE\_REFOUT = 1, SSM = 0$		15	36	ps
	RMS Phase Jitter (Random); NOTE 3		f <sub>OUT</sub> = 100MHz (12kHz – 20MHz)		1.21	1.6	ps
tjit(Ø)			f <sub>OUT</sub> = 125MHz (12kHz – 20MHz)		1.47	1.6	ps
git(Ø)			f <sub>OUT</sub> = 200MHz (12kHz – 20MHz)		1.23	1.6	ps
			f <sub>OUT</sub> = 400MHz (12kHz – 20MHz)		1.32	2	ps
$t_L$	PLL Lock Time					85	ms
$V_{MAX}$	Absolute Maximum Output Voltage; NOTE 4, 5					1150	mV
V <sub>MIN</sub>	Absolute Minimum Output Voltage; NOTE 4, 6			-300			mV
$V_{RB}$	Ringback Voltage; NOTE 7, 8			-100		100	mV
t <sub>STABLE</sub>	Time before V <sub>RB</sub> is allowed; NOTE 7, 8			500			ps
F <sub>M</sub>	SSC Modulation Frequency; NOTE 9			29	32	33.33	kHz
F <sub>MF</sub>	SSC Modulation Fa	actor; NOTE 9			-0.5		%
SSC <sub>RED</sub>	Spectral Reduction	; NOTE 9			10		dB
V <sub>CROSS</sub>	Absolute Crossing Voltage; NOTE 4, 10, 11			125		560	mV
$\Delta V_{CROSS}$	Total Variation of V <sub>CROSS</sub> ; NOTE 4, 10, 12					140	mV
t <sub>SLEW+</sub>	Rising/Falling Edge Rate; NOTE 7, 13		Measured between	0.6		4.7	V/ns
t <sub>SLEW</sub>			-150mV to +150mV	0.6		4.7	V/ns
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	REF_OUT		690		1550	ps
	Output Duty Cycle	Q[0:1], nQ[0:1]	N = 8, N = 12	45		55	%
odc		Q[0:1], nQ[0:1]	N = 6	44		56	%
	, , , , , , , ,	REF_OUT; NOTE 14	Using REF_IN Input	48		52	%

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

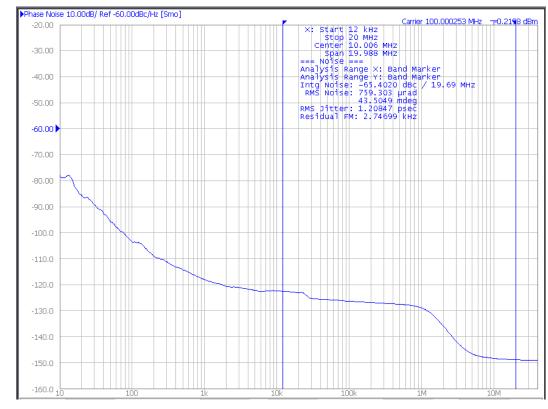
NOTE 1: Defined as skew between outputs at the same supply voltages and with equal load conditions. Measured at the output differential cross points.



- NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.
- NOTE 3: Refer to the Phase Noise Plots.
- NOTE 4: Measurement taken from single-ended waveform.
- NOTES continued on next page.
- NOTE 5: Defined as the maximum instantaneous voltage including overshoot.
- NOTE 6: Defined as the minimum instantaneous voltage including undershoot. See Parameter Measurement Information Section.
- NOTE 7: Measurement taken from a differential waveform.
- NOTE 8:  $T_{STABLE}$  is the time the differential clock must maintain a minimum  $\pm 150$ mV differential voltage after rising/falling edges before it is allowed to drop back into the  $V_{RB}$   $\pm 100$  differential range. See Parameter Measurement Information Section.
- NOTE 9: Spread Spectrum clocking enabled.
- NOTE 10: Measured at crossing point where the instantaneous voltage value of the rising edge of Qx equals the falling edge of nQx. See Parameter Measurement Information Section.
- NOTE 11: Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement. See Parameter Measurement Information Section.
- NOTE 12: Defined as the total variation of all crossing voltage of rising Qx and falling nQx. This is the maximum allowed variance in the  $V_{CROSS}$  for any particular system. See Parameter Measurement Information Section.
- NOTE 13: Measured from -150mV to +150mV on the differential waveform (derived from Qx minus nQx). The signal must be monotonic through the measurement region for rise and fall time. The 300mV measurement window is centered on the differential zero crossing. See Parameter Measurement Information Section.
- NOTE 14: REF\_OUT duty cycle characterized with REF\_IN input duty cycle between 48% and 52%.

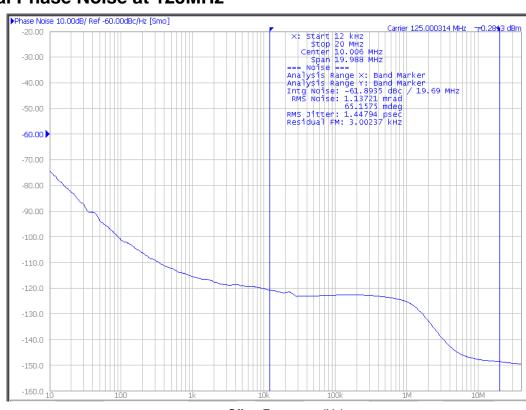


# **Typical Phase Noise at 100MHz**



Offset Frequency (Hz)

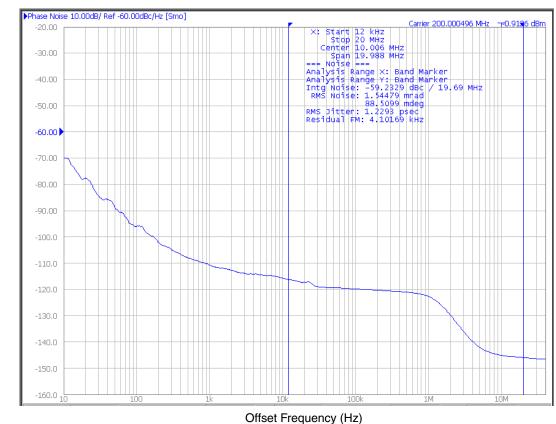
# Typical Phase Noise at 125MHz



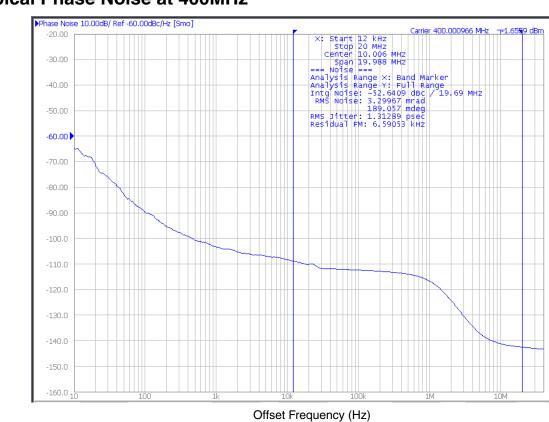
Offset Frequency (Hz)



# **Typical Phase Noise at 200MHz**

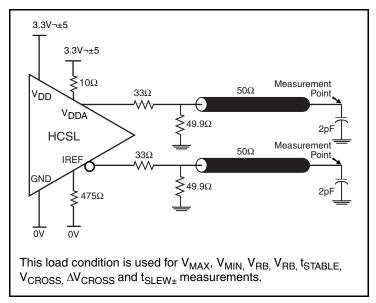


# **Typical Phase Noise at 400MHz**

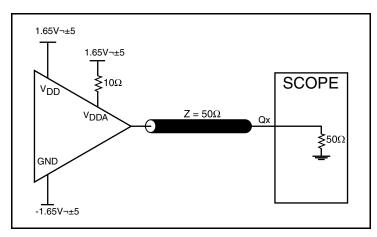




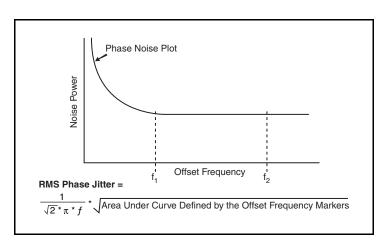
#### **Parameter Measurement Information**



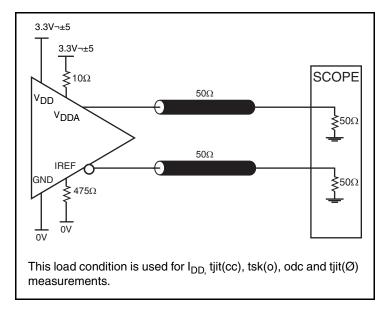
#### 3.3V HCSL Output Load AC Test Circuit



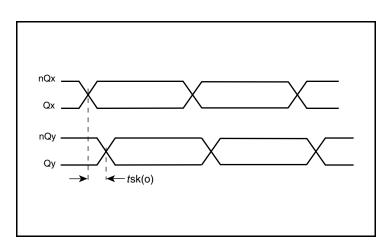
#### 3.3V LVCMOS Output Load AC Test Circuit



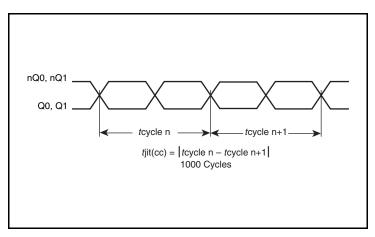
**RMS Phase Jitter** 



#### 3.3V HCSL Output Load AC Test Circuit



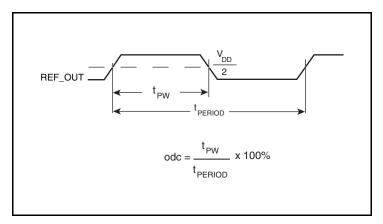
**Output Skew** 

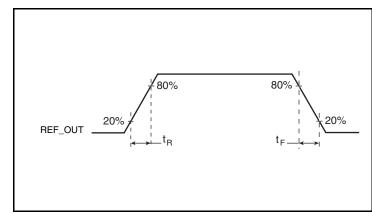


**Cycle-to-Cycle Jitter** 



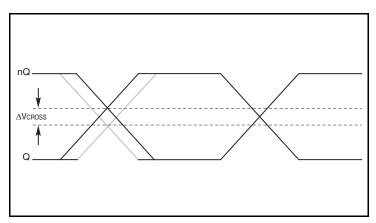
# **Parameter Measurement Information, continued**



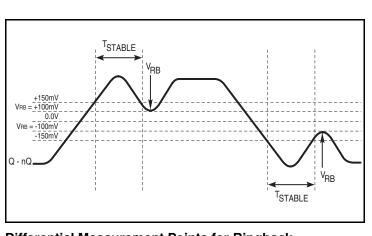


**LVCMOS Output Duty Cycle** 

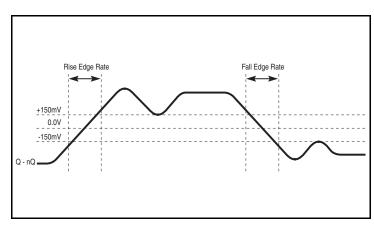
LVCMOS Rise/Fall Time



**Single-ended Measurement Points for Absolute Cross Point/Swing** 



**Single-ended Measurement Points for Delta Cross Point** 

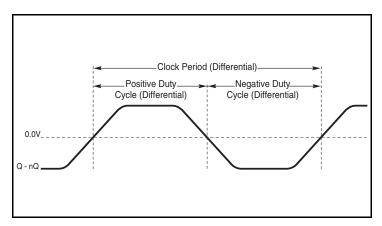


**Differential Measurement Points for Ringback** 

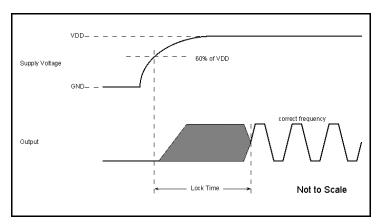
Differential Measurement Points for Rise/Fall Edge Rate



# **Parameter Measurement Information, continued**



**Differential Measurement Points for Duty Cycle/Period** 



**PLL Lock Time** 



#### **Spread Spectrum**

Spread-spectrum clocking is a frequency modulation technique for EMI reduction. When spread-spectrum is enabled, a 32kHz triangle waveform is used with 0.5% down-spread (+0.0% / -0.5%) from the nominal output frequency. An example of a triangle frequency modulation profile is shown in *Figure 1A* below. The ramp profile can be expressed as:

- Fnom = Nominal Clock Frequency in Spread Off mode (200MHz with 25MHz)
- Fm = Nominal Modulation Frequency (32kHz)
- $\delta$  = Modulation Factor (0.5% down spread)

$$(1 - \delta)$$
 Fnom + 2FM x  $\delta$  x Fnom x t when  $0 < t < \frac{1}{2Fm}$ 

$$(1 - \delta)$$
 Fnom – 2FM x  $\delta$  x Fnom x t when  $\frac{1}{2Fm}$  < t <  $\frac{1}{FM}$ 

An example of the amount of down spread relative to the nominal clock frequency can be seen in the frequency domain, as shown in *Figure 1B*. The ratio of this width to the fundamental frequency is typically 0.5%. The resulting spectral reduction is typically 10dB, as shown in *Figure 2B*. It is important to note the ICS841402I 10dB typical spectral reduction is the component-specific EMI reduction, and will not necessarily be the same as the system EMI reduction.

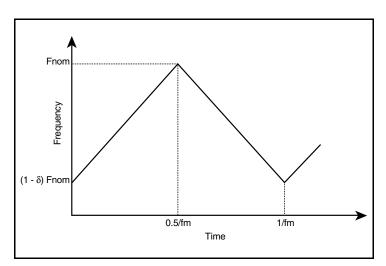


Figure 1A. Triangle Frequency Modulation

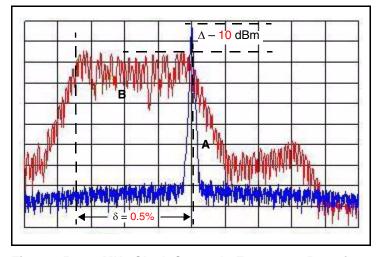


Figure 1B. 200MHz Clock Output In Frequency Domain

- (A) Spread-Spectrum OFF
- (B) Spread-Spectrum ON



# **Applications Information**

#### **Recommendations for Unused Input and Output Pins**

#### Inputs:

#### **LVCMOS Control Pins**

All control pins have internal pullups and pulldowns; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used.

#### REF\_IN

For applications not requiring the use of the reference clock, it can be left floating. Though not required, but for additional protection, a  $1k\Omega$  resistor can be tied from the REF\_IN to ground.

#### **Crystal Inputs**

For applications not requiring the use of the crystal oscillator input, both XTAL\_IN and XTAL\_OUT can be left floating. Though not required, but for additional protection, a  $1 k\Omega$  resistor can be tied from XTAL\_IN to ground.

#### **Outputs:**

#### **LVCMOS Output**

The unused LVCMOS output can be left floating. There should be no trace attached.

#### **Differential Outputs**

All unused differential outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.



#### **Overdriving the XTAL Interface**

The XTAL\_IN input can be overdriven by an LVCMOS driver or by one side of a differential driver through an AC coupling capacitor. The XTAL\_OUT pin can be left floating. The amplitude of the input signal should be between 500mV and 1.8V and the slew rate should not be less than 0.2V/nS. For 3.3V LVCMOS inputs, the amplitude must be reduced from full swing to at least half the swing in order to prevent signal interference with the power rail and to reduce internal noise. *Figure 1A* shows an example of the interface diagram for a high speed 3.3V LVCMOS driver. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This

can be done in one of two ways. First, R1 and R2 in parallel should equal the transmission line impedance. For most  $50\Omega$  applications, R1 and R2 can be  $100\Omega$ . This can also be accomplished by removing R1 and changing R2 to  $50\Omega$ . The values of the resistors can be increased to reduce the loading for a slower and weaker LVCMOS driver. Figure 1B shows an example of the interface diagram for an LVPECL driver. This is a standard LVPECL termination with one side of the driver feeding the XTAL\_IN input. It is recommended that all components in the schematics be placed in the layout. Though some components might not be used, they can be utilized for debugging purposes. The datasheet specifications are characterized and quaranteed by using a quartz crystal as the input.

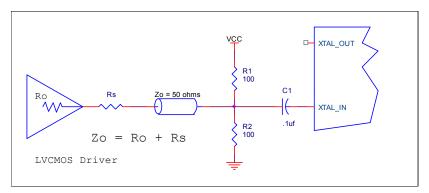


Figure 1A. General Diagram for LVCMOS Driver to XTAL Input Interface

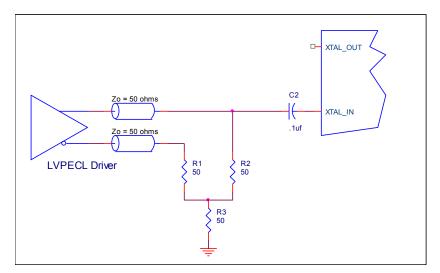


Figure 1B. General Diagram for LVPECL Driver to XTAL Input Interface



#### **VFQFN EPAD Thermal Release Path**

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 2*. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as "heat pipes". The number of vias (i.e. "heat pipes") are application specific

and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a quideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor's Thermally/ Electrically Enhance Leadframe Base Package, Amkor Technology.

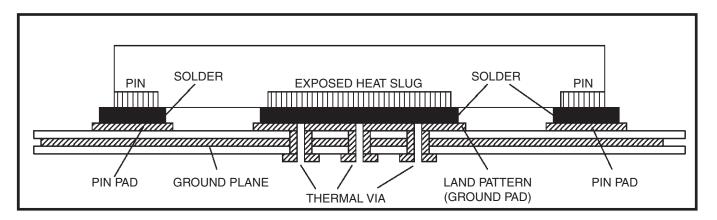


Figure 2. P.C. Assembly for Exposed Pad Thermal Release Path – Side View (drawing not to scale)



#### **PCI Express Application Note**

PCI Express jitter analysis methodology models the system response to reference clock jitter. The block diagram below shows the most frequently used *Common Clock Architecture* in which a copy of the reference clock is provided to both ends of the PCI Express Link.

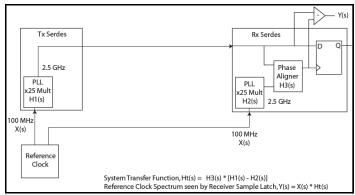
In the jitter analysis, the transmit (Tx) and receive (Rx) serdes PLLs are modeled as well as the phase interpolator in the receiver. These transfer functions are called H1, H2, and H3 respectively. The overall system transfer function at the receiver is:

$$Ht(s) = H3(s) \times [H1(s) - H2(s)]$$

The jitter spectrum seen by the receiver is the result of applying this system transfer function to the clock spectrum X(s) and is:

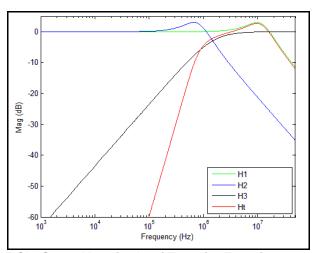
$$Y(s) = X(s) \times H3(s) \times [H1(s) - H2(s)]$$

In order to generate time domain jitter numbers, an inverse Fourier Transform is performed on X(s)\*H3(s) \* [H1(s) - H2(s)].



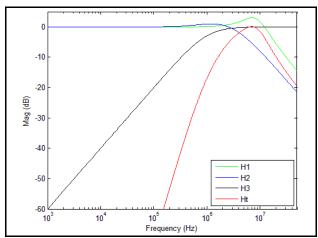
**PCI Express Common Clock Architecture** 

For **PCI Express Gen 1**, one transfer function is defined and the evaluation is performed over the entire spectrum: DC to Nyquist (e.g for a 100 MHz reference clock: 0 Hz - 50 MHz) and the jitter result is reported in peak-peak.

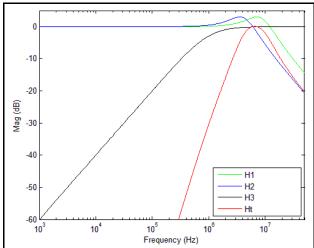


**PCle Gen 1 Magnitude of Transfer Function** 

For **PCI Express Gen 2**, two transfer functions are defined with 2 evaluation ranges and the final jitter number is reported in rms. The two evaluation ranges for PCI Express Gen 2 are 10kHz – 1.5MHz (Low Band) and 1.5MHz – Nyquist (High Band). The plots show the individual transfer functions as well as the overall transfer function Ht.

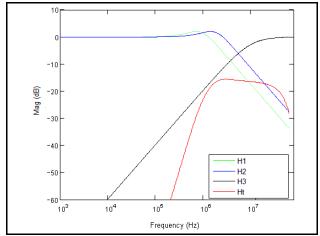


PCle Gen 2A Magnitude of Transfer Function



PCIe Gen 2B Magnitude of Transfer Function

For **PCI Express Gen 3**, one transfer function is defined and the evaluation is performed over the entire spectrum. The transfer function parameters are different from Gen 1 and the jitter result is reported in RMS.



**PCle Gen 3 Magnitude of Transfer Function** 

For a more thorough overview of PCI Express jitter analysis methodology, please refer to IDT Application Note *PCI Express Reference Clock Requirements* 



#### **Recommended Termination**

Figure 3A is the recommended source termination for applications where the driver and receiver will be on a separate PCBs. This termination is the standard for PCI Express™and HCSL output types.

All traces should be  $50\Omega$  impedance single-ended or  $100\Omega$  differential.

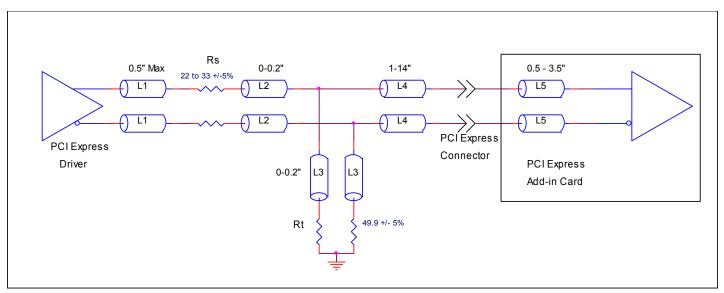


Figure 3A. Recommended Source Termination (where the driver and receiver will be on separate PCBs)

Figure 3B is the recommended termination for applications where a point-to-point connection can be used. A point-to-point connection contains both the driver and the receiver on the same PCB. With a matched termination at the receiver, transmission-line reflections will

be minimized. In addition, a series resistor (Rs) at the driver offers flexibility and can help dampen unwanted reflections. The optional resistor can range from  $0\Omega$  to  $33\Omega.$  All traces should be  $50\Omega$  impedance single-ended or  $100\Omega$  differential.

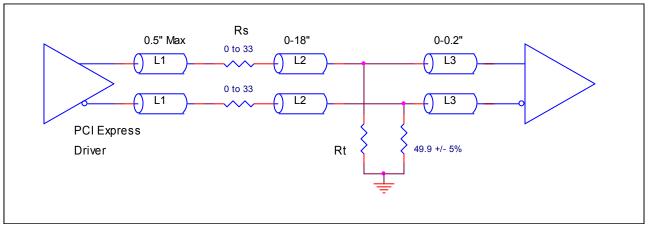


Figure 3B. Recommended Termination (where a point-to-point connection can be used)



### **Schematic Layout**

Figure 4 (next page) shows an example ICS841402I application schematic. Refer to the pin description and functional tables in the datasheet to ensure the logic control inputs are properly set. Input and output terminations shown are intended as examples only and may not represent the exact user configuration.

Resistor R11 is the specific resistor value used to match the  $17\Omega$  output impedance LVCMOS driver to the  $50\Omega$  transmission line driving REF\_IN. Load caps C1 and C2 are required for frequency accuracy and may be adjusted for different board layouts.

As with any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The ICS841402I provides separate  $V_{\mbox{\scriptsize DD}}$  and  $V_{\mbox{\scriptsize DDA}}$  power supplies to isolate any high switching noise from coupling into the internal PLL.

In order to achieve the best possible filtering, it is highly recommended that the  $0.1\mu F$  capacitors be placed on the device side of the PCB as close to the power pins as possible. This is represented by the placement of these capacitors in the schematic. If space is limited, the ferrite bead,  $10\mu F$  and  $0.1\mu F$  capacitors connected to 3.3V can be placed on the opposite side of the PCB. If space permits, place all filter components on the device side of the board.

Power supply filter recommendations are a general guideline to be used for reducing external noise from coupling into the devices. The filter performance is designed for a wide range of noise frequencies. This low-pass filter starts to attenuate noise at approximately 1 kHz. If a specific frequency noise component is known, such as switching power supplies frequencies, it is recommended that component values be adjusted and if required, additional filtering be added. Additionally, good general design practices for power plane voltage stability suggests adding bulk capacitance in the local area of all devices.



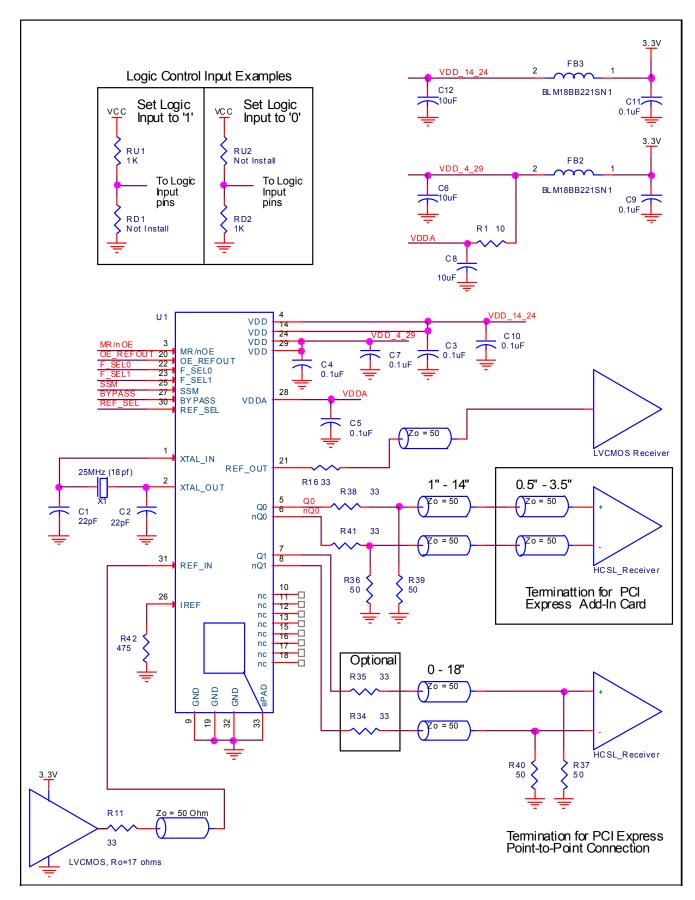


Figure 4. ICS841402I Schematic Example



#### **Power Considerations**

This section provides information on power dissipation and junction temperature for the ICS841402I. Equations and example calculations are also provided.

#### 1. Power Dissipation.

The total power dissipation for the ICS841402I is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for  $V_{DD} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)<sub>MAX</sub> =  $V_{DD MAX}$  \* ( $I_{DD} + I_{DDA}$ )= 3.465V \*(156mA + 16mA) = **596mW**
- Power (HCSL)<sub>MAX</sub> = 2 x 44.5mW = 89mW

#### **LVCMOS Driver Power Dissipation**

- Output Impedance  $R_{OUT}$  Power Dissipation due to Loading  $50\Omega$  to  $V_{DD}/2$  Output Current  $I_{OUT} = V_{DD\_MAX} / [2 * (50\Omega + R_{OUT})] = 3.465 V / [2 * (50\Omega + 27\Omega)] = 22.5mA$
- Power Dissipation on the R<sub>OUT</sub> per LVCMOS output Power (LVCMOS) = R<sub>OUT</sub> \*  $(I_{OUT})^2 = 27\Omega$  \*  $(22.5\text{mA})^2 = 13.7\text{mW}$  per output

#### **Total Power**

- = Power (core) + Power (HCSL) + Power (LVCMOS)
- = 596 mW + 89 mW + 13.7 mW
- = 698.7 mW

#### 2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, Tj, to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for Tj is as follows: Tj =  $\theta_{JA}$  \* Pd\_total + T<sub>A</sub>

Tj = Junction Temperature

 $\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

Pd\_total = Total Device Power Dissipation (example calculation is in section 1 above)

T<sub>A</sub> = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming no air flow and a multi-layer board, the appropriate value is 33.1°C/W per Table 7 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

 $85^{\circ}\text{C} + 0.699\text{W} * 33.1^{\circ}\text{C/W} = 108.2^{\circ}\text{C}$ . This is below the limit of  $125^{\circ}\text{C}$ .

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

#### Table 7. Thermal Resistance $\theta_{JA}$ for 32 Lead VFQFN, Forced Convection

<b>5.</b> 1					
$\theta_{JA}$ vs. Air Flow					
Meters per Second	0	1	3		
Multi-Layer PCB, JEDEC Standard Test Boards	33.1°C/W	28.1°C/W	25.4°C/W		



#### 3. Calculations and Equations.

The purpose of this section is to calculate power dissipation on the IC per HCSL output pair.

HCSL output driver circuit and termination are shown in Figure 5.

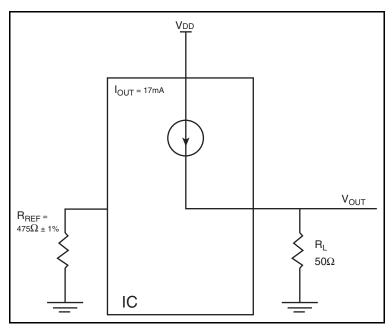


Figure 5. HCSL Driver Circuit and Termination

HCSL is a current steering output which sources a maximum of 17mA of current per output. To calculate worst case on-chip power dissipation, use the following equations which assume a  $50\Omega$  load to ground.

The highest power dissipation occurs when V<sub>DD\_MAX</sub>.

Power = 
$$(V_{DD\_MAX} - V_{OUT}) * I_{OUT}$$
  
since  $V_{OUT} = I_{OUT} * R_L$   
Power =  $(V_{DD\_MAX} - I_{OUT} * R_L) * I_{OUT}$   
=  $(3.465V - 17mA * 50\Omega) * 17mA$ 

Total Power Dissipation per output pair = 44.5mW



# **Reliability Information**

# Table 8. $\theta_{\text{JA}}$ vs. Air Flow Table for a 32 Lead VFQFN

$\theta_{JA}$ vs. Air Flow					
Meters per Second	0	1	3		
Multi-Layer PCB, JEDEC Standard Test Boards	33.1°C/W	28.1°C/W	25.4°C/W		

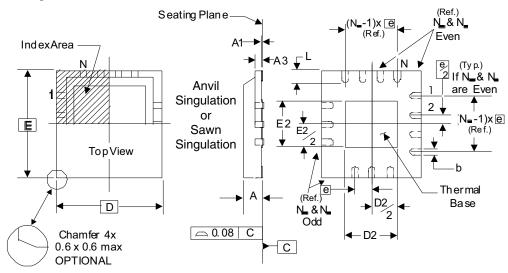
### **Transistor Count**

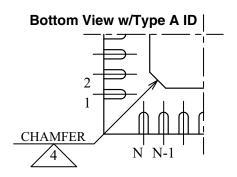
The transistor count for ICS841402I is: 12,330

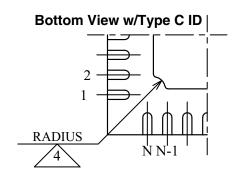


### **Package Outline and Package Dimensions**

#### Package Outline - K Suffix for 32 Lead VFQFN







There are 2 methods of indicating pin 1 corner at the back of the VFQFN package are:

- 1. Type A: Chamfer on the paddle (near pin 1)
- 2. Type C: Mouse bite on the paddle (near pin 1)

**Table 9. Package Dimensions** 

JEDEC Variation: VHHD-2/-4 All Dimensions in Millimeters						
Symbol	Minimum	Nominal	Maximum			
N		32				
Α	0.80		1.00			
<b>A</b> 1	0 0.05					
А3	0.25 Ref.					
b	0.18	0.25	0.30			
N <sub>D</sub> & N <sub>E</sub>			8			
D&E	5.00 Basic					
D2 & E2	3.0		3.3			
е	0.50 Basic					
L	0.30	0.40	0.50			

Reference Document: JEDEC Publication 95, MO-220

NOTE: The following package mechanical drawing is a generic drawing that applies to any pin count VFQFN package. This drawing is not intended to convey the actual pin count or pin layout of this device. The pin count and pinout are shown on the front page. The package dimensions are in Table 9.



# **Ordering Information**

# **Table 10. Ordering Information**

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
841402DKILF	ICS41402DIL	"Lead-Free" 32 Lead VFQFN	Tray	-40°C to 85°C
841402DKILFT	ICS41402DIL	"Lead-Free" 32 Lead VFQFN	Tape & Reel	-40°C to 85°C



# **Revision History Sheet**

Rev	Table	Page	Description of Change	
Α	4A	4	I <sub>DD</sub> , I <sub>DDA</sub> ; Test Conditions; added "Outputs Unterminated"	11/7/12



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